

30V N-Channel Power MOSFET



SOT-23



Pin Definition:

- 1. Gate
- 2. Source
- 3. Drain

Note:

MSL 1 (Moisture Sensitivity Level) per J-STD-020

Key Parameter Performance

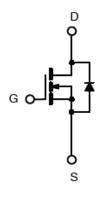
Parameter		Value	Unit	
V_{DS}		30	V	
R _{DS(on)} (max)	V _{GS} = 10V	24	mΩ	
	V _{GS} = 4.5V	34		
Q_g		4.1	nC	

Ordering Information

Ordering code	Package	Packing		
TSM240N03CX RFG	SOT-23	3kpcs / 7" Reel		

Note: Halogen-free according to IEC 61249-2-21 definition

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings (T_C = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	±20	V	
Continuous Drain Current	$T_C = 25^{\circ}C$	· I _D	6.5	А	
	T _C = 100°C		4.1	Α	
Pulsed Drain Current (Note 1)		I _{DM}	26	Α	
Single Pulse Avalanche Energy (Note 2)		E _{AS}	32	mJ	
Power Dissipation @ T _C = 25°C		P _D	1.56	W	
Operating Junction Temperature		TJ	150	°C	
Storage Temperature Range		T _{STG}	-55 to +150	°C	

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Ambient	$R_{\Theta JA}$	80	°C/W

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Electrical Specifications (T_C = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	30			V
	$V_{GS} = 10V, I_D = 6A$	R _{DS(on)}		17	24	mΩ
Drain-Source On-State Resistance	V _{GS} = 4.5V, I _D = 4A			22	34	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	V _{GS(TH)}	1.2	1.4	2.5	V
	$V_{DS} = 30V, V_{GS} = 0V$				1	μΑ
Zero Gate Voltage Drain Current	V _{DS} = 24V, T _J = 125°C	I _{DSS}			10	
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	μΑ
Forward Transconductance (Note 3)	$V_{DS} = 10V, I_{D} = 4A$	g _{fs}		6.5		S
Dynamic				L	•	I
Total Gate Charge (Note 3,4)		Q_g		4.1		
Gate-Source Charge (Note 3,4)	$V_{DS} = 15V, I_{D} = 6A,$	Q_{gs}		1		nC
Gate-Drain Charge (Note 3,4)	$V_{GS} = 4.5V$	Q_{gd}		2.1		
Input Capacitance		C _{iss}		345		
Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz	C _{oss}		55		pF
Reverse Transfer Capacitance		C_{rss}		32		
Switching	-					I.
Turn-On Delay Time (Note 3,4)		t _{d(on)}		2.8		
Turn-On Rise Time (Note 3,4)	$V_{DD} = 15V, I_{D} = 1A,$	t _r		7.2		
Turn-Off Delay Time (Note 3,4)	$V_{GS} = 10V, R_G = 6\Omega$	t _{d(off)}		15.8		ns
Turn-Off Fall Time (Note 3,4)		t _f		4.6		1
Source-Drain Diode Ratings and Ch	aracteristic			L	•	I
Maximum Continuous Drain-Source		ı			6.5	۸
Diode Forward Current	Integral reverse diode in the MOSFET	I _S			0.5	Α
Maximum Pulse Drain-Source Diode		I _{SM}			26	Α
Forward Current						
Diode-Source Forward Voltage	$V_{GS} = 0V$, $I_S = 1A$	V_{SD}			1	V

Note:

- 1. Pulse width limited by safe operating area
- 2. L = 1mH, $I_{AS} = 8A$, $V_{DD} = 25V$, $R_G = 25\Omega$, Starting $T_J = 25^{\circ}C$
- 3. Pulse test: pulse width \leq 300µs, duty cycle \leq 2%
- 4. Switching time is essentially independent of operating temperature.

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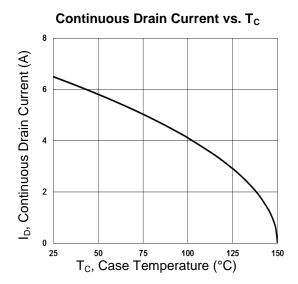


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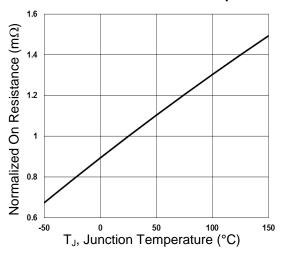
Gate Charge



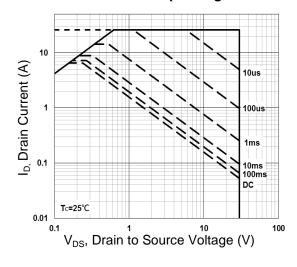
Electrical Characteristics Curve

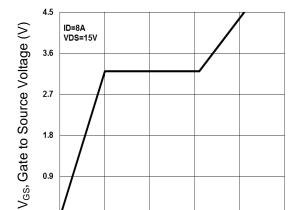


On-Resistance vs. Junction Temperature



Maximum Safe Operating Area



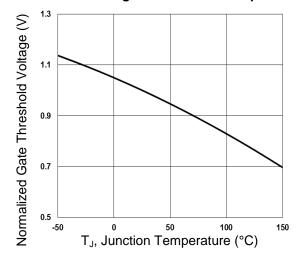


0.9

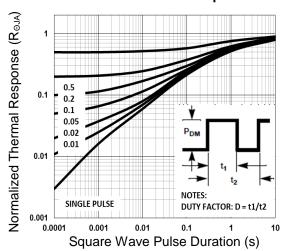
0

Threshold Voltage vs. Junction Temperature

Qg, Gate Charge (nC)



Normalized Thermal Transient Impedance Curve



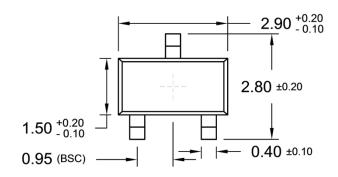
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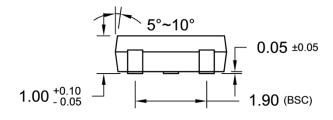


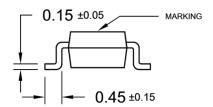
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SOT-23 Mechanical Drawing

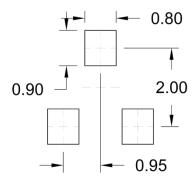






Unit: Millimeters

SUGGESTED PAD LAYOUT (Unit: Millimeters)



Marking Diagram



24 = Device Code

Y = Year Code

M = Month Code for Halogen Free Product (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)

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L = Lot Code

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TSM240N03CX 30V N-Channel Power MOSFET

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